Electrons in bilayer graphene exhibit quite unusual properties: they can be viewed as “massive chiral fermions” with parabolic dispersion at intermediate energies and Berry phase. In contrast to monolayer graphene, where charge carriers are Berry-phase-π quasiparticles with linear dispersion, they can be viewed as “massive chiral fermions” with quasiparticles with linear dispersion. Here, we show that the topology of the low-energy band structure of electrons in bilayer graphene critically depends on mechanical deformations of the crystal. Strain determines the number of Dirac mini-cones in the low-energy part of the spectrum, below the saddle point in the electron dispersion: two with the Berry phases π in a strongly strained crystal instead of four (three with Berry phase π and one with −π) in an unperturbed crystal. These spectral features are tracked down to the evolution of the Landau levels for electrons in a magnetic field, and we predict their manifestation in the quantum Hall effect in strained bilayers. We show that topology of the low-energy band structure in bilayer graphene critically depends on mechanical deformations of the crystal which may easily develop in suspended graphene flakes. We describe the Lifshitz transition that takes place in strained bilayers upon splitting the parabolic bands at intermediate energies into several Dirac cones at the energy scale of a few meV. Then, we show how this affects the electron Landau level spectra and the quantum Hall effect.

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Strained bilayer graphene: Band structure topology and Landau level spectrum

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We show that topology of the low-energy band structure in bilayer graphene critically depends on mechanical deformations of the crystal which may easily develop in suspended graphene flakes. We describe the Lifshitz transition that takes place in strained bilayers upon splitting the parabolic bands at intermediate energies into several Dirac cones at the energy scale of a few meV. Then, we show how this affects the electron Landau level spectra and the quantum Hall effect.

FIG. 1. (Color online) Top: Top view of the unperturbed (left) and deformed (right) bilayer graphene lattice. The top and bottom graphene layers are shown in yellow (light) and blue (dark), respectively. Bottom: Electronic band structure of unperturbed bilayer graphene in the vicinity of the Brillouin zone corners $K$ and $K'$.
\[ \partial_t \text{Im} A_0, \text{ whereas } \tilde{A}_0 = 0 \text{ for any homogeneous strain. Also, } m = \frac{2\hbar^2}{\gamma_1 r_{AB}^2} \approx 0.035m_e \text{ is the effective mass in the parabolic dispersion, } \epsilon \approx \frac{e^2}{\epsilon}, \text{ of electrons at intermediate energies } \gamma_1 > \epsilon > \max(mv_F^2, w); \text{ and } v_3 = \frac{\gamma_3}{\gamma_2 r_{AB}}/\hbar. \]

The nontrivial effect of strain in Eq. (1) cannot be captured by the theories neglecting the skew coupling \( \gamma_2 \), and the effect of strain is most significant at low energies, \(|\epsilon| \lesssim \max(mv_F^2, w)\).

To derive the effective Hamiltonian (1), we had to take into account that deformations modify coupling elements for the intralayer hops \( A_{1(2)} = B_{1(2)} \) and interlayer skew hops \( A_1 - B_2 \) in directions \( e_n \), \( n = 1, 2, 3 \),

\[
\begin{align*}
\frac{\gamma_0}{\gamma_0} &= 1 + \left( \frac{\delta - \delta^*}{2} e_n \cdot l + \frac{\delta + \delta^*}{2} \right) \eta_0, \\
\frac{\gamma_2}{\gamma_0} &= 1 + \left[ e_n \cdot \left( \frac{\delta^* - \delta}{2} r_{AB} \right) + \frac{\delta + \delta^*}{2} \right] \eta_3.
\end{align*}
\]

Here, \( l = (\sin 2\theta, \cos 2\theta) \). These couplings enter the closest-neighbor tight-binding model for bilayers,

\[ \hat{H}_{t.b.} = -\sum_{i=1,2} \sum_{r_{ij}} \sum_{r_{kl}} \left( \gamma_0 \gamma_2 \right) c_{r_{ij}}^\dagger c_{r_{kl}} + \text{H.c.} \]

\[ + \sum_{r_{ij}} \sum_{r_{kl}} \left( \gamma_2 \right) c_{r_{ij}}^\dagger c_{r_{kl}} + \text{H.c.} \]

\[ + \sum_{r_{ij}} \left( \gamma_2 \right) c_{r_{ij}}^\dagger c_{r_{ij}} + \text{H.c.}. \]

Here, \( c^\dagger (c) \) are creation (annihilation) operators for electrons on the corresponding lattice sites, whereas the vectors \( e_n \) differentiate between three directions of the \( A - B \) hops. Note that in Eq. (2), the terms with \( (\delta + \delta^*) \) account for “hydrostatic” rescaling of the lattice period and only affect the values of \( m \) and \( v_3 \). Also, the direct \( A_1 - B_1 \) interlayer coupling, \( \gamma_1 \), may be changed by shear, \( \gamma_1 \rightarrow \gamma_1 + \Omega r_{AB} \), without any bearing on the topology of electron bands at low energies.

For the electron Bloch states on the sublattice \( A_1, B_2, A_2, \) and \( B_1 \), for the wave vectors in the vicinity of the Brillouin zone corners \( K \) and \( K' \) (note that strain distorts the hexagonal shape of the Brillouin zone, which we also take into account), the four-band Hamiltonian for the electrons has the form

\[
\hat{H} = \begin{pmatrix}
0 & \xi v_3 \hat{\sigma} + A_3 & 0 & \xi v_3 \hat{\sigma} + A_0 \\
\xi v_3 \hat{\sigma} + A_3 & 0 & \xi v_3 \hat{\sigma} + A_0 & 0 \\
0 & \xi v_3 \hat{\sigma} + A_0 & 0 & \gamma_1 \\
\xi v_3 \hat{\sigma} + A_0 & 0 & \gamma_1 & 0
\end{pmatrix},
\]

where \( \hat{\sigma} = p_x + ip_y \), and \( v = \frac{\gamma_3}{\gamma_2 r_{AB}}/\hbar \) is the Dirac velocity in the monolayer. Following the suggestion$^{12}$ that in monolayers the effect of homogeneous strain appears as constant vector potential equivalent to a small shift of the valley center from the Brillouin zone corners, here, we employ gauge transformation of the sublattice spinor \( \psi \rightarrow \psi \exp(-i\xi \phi) \) which moves the potential part \( (\partial_t + i\partial_\phi) \phi \) of \( A_0 \) from the antidiagonal part

FIG. 2. (Color online) Calculated low-energy electronic dispersions in the conduction band of strained BLG and fan plots of Landau levels. Dispersion is plotted for the states near the Brillouin zone corners shown in Fig. 1 at energies \(|\epsilon| < 10 \text{ meV} \) and for momentum in the units of \( p^* = mv_F \), for several representative points in the (Re \( w, \text{Im } w \)) space, as marked in Fig. 3(a). Spikes at the bottom of dispersion surfaces are the Dirac points characterized by Berry phases \( \pm \pi \). For the Landau levels, boxed numbers mark their degeneracy.
of the four-band Hamiltonian into the diagonal $2 \times 2$ block and add (subtract) $\frac{1}{\hbar} \hat{A}_3$ to $\hat{H}_1(A_1)$ in the diagonal block. After this, we use the Schrieffer-Wolff transformation\(^{11}\) to project the four-band Hamiltonian onto the pair of low-energy bands\(^1\) describing electron states located predominantly on the sublattices $A_1$ and $B_2$, and, finally, arrive at the two-band Hamiltonian in Eq. (1).

To judge the significance of strain, one needs to know the values of lattice parameters $\eta_0$ and $\eta_3$. Although the value of $\eta_3$ is not known, analysis of Raman spectra of monolayers\(^{14}\) suggests that $\eta_0 \approx 3$, and we estimate that 1% of strain would lead to $|w| \sim 6 \text{ meV}$. This can be further enhanced by the electron-electron interaction, which we confirm by incorporating the new strain-induced term in the Hamiltonian (1) into the earlier-developed renormalization group theory for BLG parameters.\(^\text{15}\) The calculation, based upon the use of dynamically screened Coulomb interaction and the method of $\frac{1}{\hbar} \chi$ expansion ($N = 4$ is the number of electron species in BLG: 2 spin and 2 valley), yields in the renormalization group flow,

\[
\partial_t w = 0.11 w, \quad \partial_t m^{-1} = -0.02 m^{-1}, \quad \partial_t v_3 = -0.02 v_3,
\]

where $\lambda = \ln \frac{2}{\epsilon}$ and $\epsilon$ is the running energy scale. The electron-electron interaction enhances the strain-induced term more strongly than other parameters, and at energies $\epsilon \sim |w|$, where the influence of strain plays a dominant role in determining the electron spectrum, we substitute

\[
|w| \rightarrow |w| \exp \left( 0.11 \ln \frac{w}{|w|} \right) \approx |w|^{0.89} y_1^{0.11}, \tag{3}
\]

in the Hamiltonian (1), leading for 1% strain to an increase from 6 meV to the interaction-corrected estimate, $|w| \sim 9 \text{ meV}$. The change in topology of the low-energy dispersion for electrons\(^{16}\) is shown in Fig. 2 for several representative values of homogeneous strain chosen from three characteristic regimes distinguished by shading in Fig. 3(a). These dispersions are plotted for the conduction band in the valley $K$ (to be inverted in the momentum space to describe valley $K'$ and flipped over for the valence band states, $e \rightarrow -e$). For $w = 0$, electron dispersion undergoes Lifshitz transition\(^{17}\) at the energy of the saddle point in the dispersion, $\epsilon^* = mv_3^2/2$; it splits from a single-connected, almost circular line into few disconnected parts, each corresponding to a separate Dirac cone.\(^1\) Small strain, $|w| \lesssim \epsilon^*$, shifts these Dirac cones across the momentum plane, as shown in Fig. 2 for $w = \epsilon^*$ and $w = -i \epsilon^*$. A stronger strain results in a collision annihilating two Dirac points, one with the Berry phase $-\pi$ and another with $+\pi$, which results in a local minimum in the dispersion, as illustrated for $w = -5 \epsilon^*$ and $w = -3i \epsilon^*$. The other two Dirac points, each with the Berry phase $+\pi$, continue to exist. In Fig. 3(a), the parametric regime where, in addition to a pair of well-separated Dirac cones, the dispersion has a local minimum is marked by dark shading. Finally, much larger strain [light shading in Fig. 3(a)] removes the local minimum in the dispersion, resulting in an even larger separation between the remaining Dirac cones and in a saddle point at $|\epsilon| \approx |w|$, which determines the deformation-dependent Lifshitz transition energy in strained BLG. Note that all these spectral changes take place at a relatively low strain, $\sim 1\%$, compared with the strain of over 20%\(^\text{18}\) required to merge Dirac points in monolayer graphene.\(^\text{19}\)

The transformation of electron dispersion by a homogeneous strain leads to the modification of the BLG Landau level (LL) spectrum. The examples of numerically calculated LLs are shown in Fig. 2 for low magnetic fields, $B < 0.4 \text{ T}$. Both for small and large strain, the high-magnetic-field end of the LL fan plot, $h\omega_c \equiv hB/m \gg \max(\epsilon^*, |w|)$, is approximately described by the sequence $\epsilon \approx \pm \sqrt{n(n - 1)}\bar{\epsilon}_0$, of four-fold degenerate LLs at nonzero energy ($n > 2$) and an eightfold degenerate LL at $\epsilon = 0$ ($n = 0.1$).\(^1\) In nonstrained BLG at low fields, such that $h\omega_c(B) < mv_3^2$, this transforms into a 16-fold degenerate LL at $\epsilon = 0$, so that the largest gap in the LL spectrum is between the $\epsilon = 0$ and next excited LL, suggesting the persistence of filling factor $\nu = \pm 8$ in the quantum Hall effect (QHE) at low magnetic fields. After strain causes the annihilation of two out of four Dirac points, the $\epsilon = 0$ level becomes 8-fold degenerate, and, for strain $|w| > \epsilon^*$, only filling factors $\nu = +4$ and $\nu = -4$ persist in the low-field QHE in BLG: the largest energy gap in the LL spectra is between the 8-fold degenerate level at $\epsilon = 0$ and the next excited level, whereas the rest of the spectrum is quite dense. This 8-fold degeneracy is topologically protected and it also appears in a rotationally twisted two-layer stack.\(^\text{20}\) Figures 3(b)–3(d) show, for each of the three characteristic regimes of strain in Fig. 3(a), how the inter-LL separation (which determines the activation energy of the low-energy spectrum) changes with the magnetic field.

FIG. 3. (Color online) (a) Parametric regimes of complex $w$ in Eq. (1), distinguishing between three characteristic topologies of the BLG spectrum in Fig. 2. (b)–(d) Activation energies for the QHE in strained BLG with various integer filling factors. For a large enough strain, (c) and (d), filling factor $\nu = \pm 4$ would be the only persistent feature in the low-field QHE. The appearance of a local minimum in the electron dispersion upon a collision of two Dirac points is manifested in (c) by an intermediate saturation of $\epsilon_{\text{sat}}(B)$ within the interval $0.2 < B < 0.4 \text{ T}$.
energies, $\epsilon_{\text{act}}$, in the QHE) varies from high to low magnetic fields. At the high field end, $\hbar \omega_c \gg |w|$, where the LL spectrum is determined by the quadratic term in Eq. (1), $\epsilon_{\text{act}} \sim \hbar \omega_c \propto B$. For the lowest fields, the gap between $\epsilon = 0$ and the next LL scales as $\epsilon_{\text{act}} \propto \sqrt{B}$, typically for the Dirac-type dispersion emerging upon the Lifshitz transition. This behavior is more pronounced for larger strain. In the regime of intermediate strain corresponding to the dark area in Fig. 3(a), the activation energy $\epsilon_{\text{act}}$ of the $\nu = 4$ state experiences a very unusual intermediate saturation illustrated in Fig. 3(c), indicating that one of the LLs gets stuck in the local dispersion minimum illustrated in Fig. 2. These results are applicable locally in the case of inhomogeneous strain, using $B_{\text{eff}} = B + \xi B_{\text{eff}}$ (Ref. 21), which lifts the valley degeneracy of the LLs, as long as the strain varies smoothly on the scale longer than the effective magnetic length $\lambda = \sqrt{\hbar/eB}$.

To summarize, using homogeneous strain, one can spectacularly change the topology of the low-energy electron dispersion, collide, and annihilate Berry phase $\pm \pi$ Dirac points near the corners of the Brillouin zone of a bilayer graphene crystal. The topological changes in the dispersion of electrons result in the dominance of specifically $\nu = \pm 4$ states in the QHE in BLG at low magnetic fields, with a characteristic behavior of the activation energy as a function of a magnetic field. The latter features should be viewed in the context of the on-going experimental studies of fundamental properties of bilayers: they offer the possibility of distinguishing the effects of the deformations from spectral changes accompanying the earlier-suggested phase transitions into ferromagnetic22 or ferroelectric23,24 states related to the electron-electron interactions, which are now being searched for in suspended BLG devices.8–10 The latter should differ by opening a gap in the BLG spectrum. However, the “nematic” phase of the electron liquid15,25 leads to the same spectral changes as uniaxial strain.

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5J. C. Slonczewski and P. R. Weiss, Phys. Rev. 109, 272 (1958);
20R. de Gail et al., e-print arXiv:1103.3172.